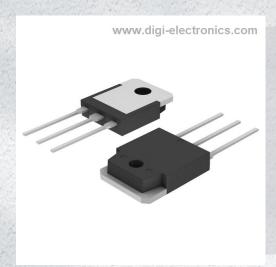


FQA19N60 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number FQA19N60-DG

Manufacturer onsemi

Manufacturer Product Number FQA19N60

Description MOSFET N-CH 600V 18.5A TO3PN

Detailed Description N-Channel 600 V 18.5A (Tc) 300W (Tc) Through Hol

TO-3PI



Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:		
FQA19N60	onsemi		
Series:	Product Status:		
QFET®	Obsolete		
FET Type:	Technology:		
N-Channel	MOSFET (Metal Oxide)		
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:		
600 V	18.5A (Tc)		
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:		
10V	380mOhm @ 9.3A, 10V		
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:		
5V @ 250μA	90 nC @ 10 V		
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:		
±30V	3600 pF @ 25 V		
FET Feature:	Power Dissipation (Max):		
	300W (Tc)		
Operating Temperature:	Mounting Type:		
-55°C ~ 150°C (TJ)	Through Hole		
Supplier Device Package:	Package / Case:		
TO-3PN	TO-3P-3, SC-65-3		
Base Product Number:			
FOA19			

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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April 2014



FQA19N60

N-Channel QFET® MOSFET

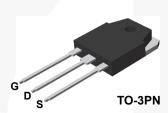
600 V, 18.5 A, $380 \text{ m}\Omega$

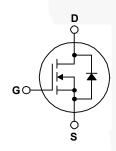
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 18.5 A, 600 V, R_{DS(on)} = 380 m Ω (Max.) @ V_{GS} = 10 V, I_D = 9.3 A
- Low Gate Charge (Typ. 70 nC)
- · Low Crss (Typ. 35 pF)
- · 100% Avalanche Tested





Absolute Maximum Ratings $T_c = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter		FQA19N60	Unit
V _{DSS}	Drain-Source Voltage		600	V
I _D	Drain Current - Continuous (T _C = 25°	C)	18.5	А
	- Continuous (T _C = 100)°C)	11.7	А
I _{DM}	Drain Current - Pulsed	(Note 1)	74	А
V _{GSS} Gate-Source Voltage			± 30	V
E _{AS} Single Pulsed Avalanche Energy		sed Avalanche Energy (Note 2) 1150		mJ
I _{AR}	Avalanche Current (N		18.5	Α
E _{AR}	Repetitive Avalanche Energy (Note		30	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3		4.5	V/ns
P _D Power Dissipation (T _C = 25°C)			300	W
- Derate above 25°C			2.38	W/°C
T_J , T_{STG}	, T _{STG} Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temperature for Soldering	ng,	300	°C
· L	1/8" from Case for 5 Seconds		1	

Thermal Characteristics

Symbol	Parameter	neter FQA19N60	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.42	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.24	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	40	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQA19N60	FQA19N60	TO-3PN	Tube	N/A	N/A	30 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	600			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.65		V/°C
I _{DSS}	Zara Cata Valtaga Drain Current	V _{DS} = 600 V, V _{GS} = 0 V			10	μΑ
	Zero Gate Voltage Drain Current	V _{DS} = 480 V, T _C = 125°C			100	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V	-		100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$		1	-100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} =10 V, I _D =9.3 A		0.3	0.38	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 50 \text{ V}, I_{D} = 9.3 \text{ A}$		16		S
Dynam	ic Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,	\	2800	3600	pF
Coss	Output Capacitance	f = 1.0 MHz		350	450	pF
C _{rss}	Reverse Transfer Capacitance			35	45	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 300 V, I _D = 18.5 A,		65	140	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		210	430	ns
t _{d(off)}	Turn-Off Delay Time			150	310	ns
t _f	Turn-Off Fall Time	(Note 4)		135	280	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 18.5 A,	/	70	90	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V	/	17		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		33		nC
Drain-S	Source Diode Characteristics ar	nd Maximum Ratings				
Maximum Continuous Drain-Source Diode Forward Current					18.5	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				74	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 18.5 A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 18.5 A,		420		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		4.7		μС

- Notes: Notes: A Repetitive rating: pulse-width limited by maximum junction temperature. 2. L = 6.2 mH, I_{AS} = 18.5 A, V_{DD} = 50 V, R_{C} = 25 Ω , starting T_{J} = 25°C. 3. I_{SD} ≤ 18.5 A, di/dt ≤ 200 A/ μ s, V_{DD} ≤ BV $_{DSS}$, starting T_{J} = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

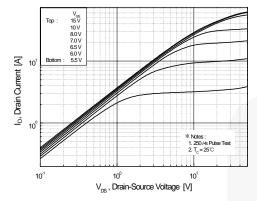


Figure 1. On-Region Characteristics

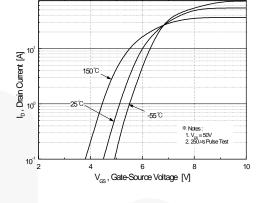


Figure 2. Transfer Characteristics

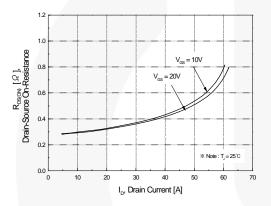


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

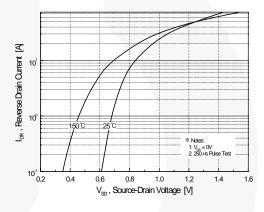


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

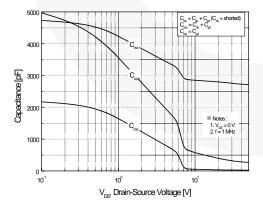


Figure 5. Capacitance Characteristics

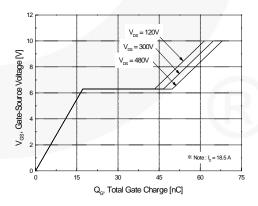
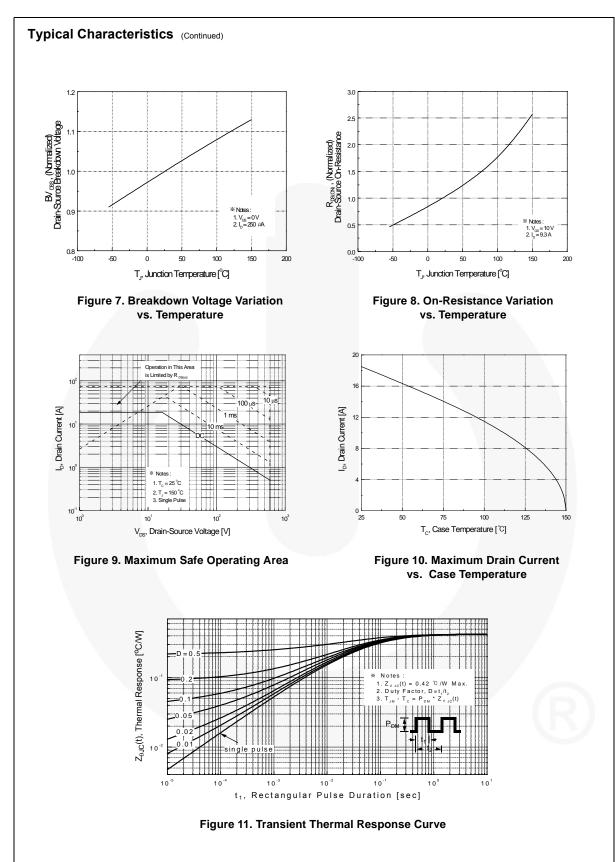


Figure 6. Gate Charge Characteristics



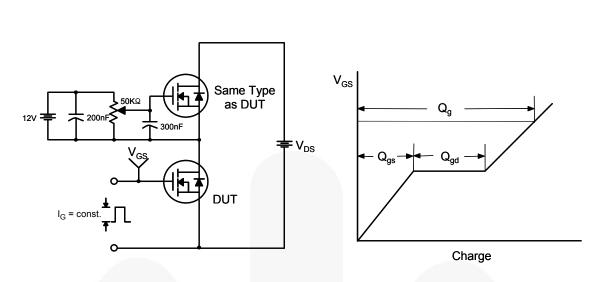


Figure 12. Gate Charge Test Circuit & Waveform

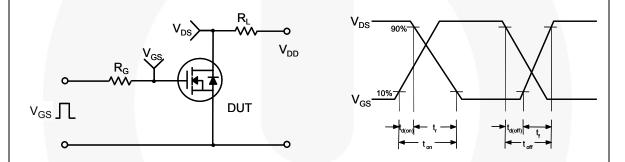


Figure 13. Resistive Switching Test Circuit & Waveforms

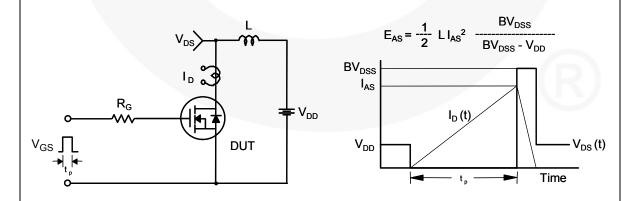
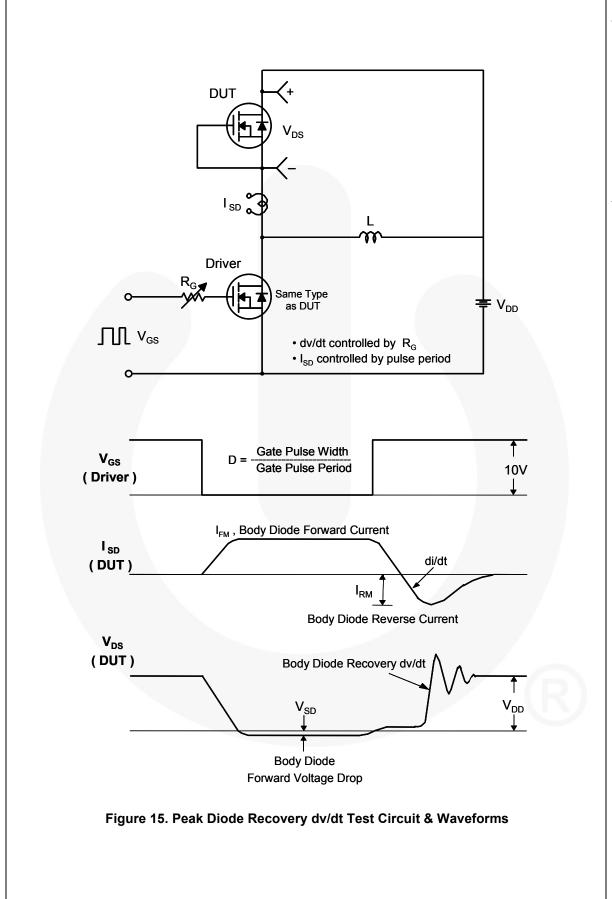
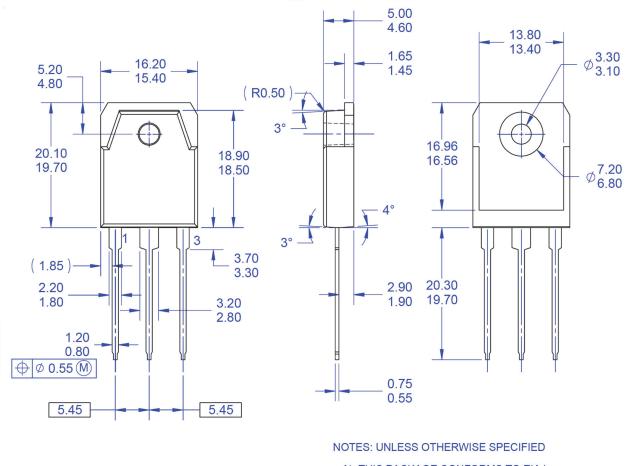


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions



(R0.50)

- A) THIS PACKAGE CONFORMS TO EIAJ SC-65 PACKAGING STANDARD.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- **DIMENSION AND TOLERANCING PER** ASME14.5-2009.
- D) DIMENSIONS ARE EXCLUSSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSSIONS.
 E) DRAWING FILE NAME: TO3PN03AREV1.
- FAIRCHILD SEMICONDUCTOR.

Figure 16. TO3PN, 3-Lead, Plastic, EIAJ SC-65

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